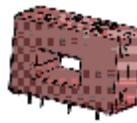


K-No.: 25150

125 A Current Sensor

For the electronic measurement of currents:
DC, AC, pulsed, mixed ..., with a galvanic isolation
between the primary circuit (high power)
and the secondary circuit (electronic circuit)



Date: 20.10.2010

Customer: Standard type

Customers Part no.:

Page 1 of 2

Description

- Closed loop (compensation)
- Current Sensor with magnetic field probe
- Printed circuit board mounting
- Casing and materials UL-listed

Characteristics

- Excellent accuracy
- Very low offset current
- Very low temperature dependency and offset current drift
- Very low hysteresis of offset current
- Short response time
- Wide frequency bandwidth
- Compact design
- Reduced offset ripple

Applications

- Mainly used for stationary operation in industrial applications:
- AC variabel speed drives and servo motor drives
 - Static converters for DC motor drives
 - Battery supplied applications
 - Switched Mode Power Supplies (SMPS)
 - Power Supplies for welding applications
 - Uninterruptable Power Supllies (UPS)

Electrical data – Ratings

I _{PN}	Primary nominal r.m.s. current	125	A
R _M	Measuring resistance V _C =± 12V	5 ... 250	Ω
	V _C =± 15V	18...400	Ω
I _{SN}	Secondary nominal r.m.s. current	125	mA

K_N

Turns ratio

1: 1000

Accuracy – Dynamic performance data

		min.	typ.	max.	Unit
I _{P,max}	Max. measuring range @ V _C = ±12V, R _M = 14 Ω (t _{max} = 10sec) @ V _C = ±15V, R _M = 25 Ω (t _{max} = 10sec)	±201			A
X	Accuracy @ I _{PN} , T _A = 25°C	±214			A
ε _L	Linearity	0.1	0.5	0.5	%
I ₀	Offset current @ I _P =0, T _A = 25°C	0.03	0.1	0.1	mA
t _r	Response time	1			μs
Δt (I _{P,max})	Delay time at di/dt = 100 A/μs	0.5			μs
f	Frequency bandwidth	DC...100			kHz

General data

		min.	typ.	max.	Unit
T _A	Ambient operating temperature	-40	+85	+85	°C
T _S	Ambient storage temperature	-40	+90	+90	°C
m	Mass	30			g
V _C	Supply voltage	±11.4	±12/±15	±15.75	V
I _C	Current consumption	18			mA
	Constructed and manufactured and tested in accordance with EN 61800-5-1 (Pin 1- 4 to inner hole) Reinforced insulation, Insulation material group 1, Pollution degree 2				
S _{clear}	Clearance (component without solder pad)	12			mm
S _{creep}	Creepage (component without solder pad)	12			mm
V _{sys}	System voltage overvoltage category 3	RMS	600	600	V
V _{work}	Working voltage (table 7 acc. to EN61800-5-1)				
	Over voltage category 2	RMS	1000	1000	V
U _{PD}	Rated discharge voltage	peak value	1225	1225	V

Maximal continuous and peak currents at defined temperatures**Supply voltage ±12V:**

T _A	85 °C	85 °C	70 °C	55 °C
I _P	125 A	100 A	130 A	150 A
I _{P,max}	205 A	224 A	255 A	262 A
R _M	14 Ω	10 Ω	5 Ω	5 Ω

Supply voltage ±15V:

T _A	85 °C	85 °C	70 °C	55 °C
I _P	125 A	80 A	100 A	125 A
I _{P,max}	176 A	218 A	223 A	255 A
R _M	39 Ω	25 Ω	25 Ω	18 Ω

Date Name Issue Amendment

20.10.10 Le 81 Mechanical outline – Error correction – distance of fastening bores (41,4 to 40,64) lapidary change.

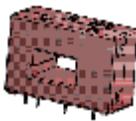
Hrsg.: KB-E
editorBearb: Le.
designerKB-PM: KRe
checkfreig.: prs.
released

Copying of this document, disclosing it to third parties or using the contents there for any purposes without express written authorization by use illegally forbidden
Any offenders are liable to pay all relevant damages.

K-No.: 25150

125 A Current Sensor

For the electronic measurement of currents:
DC, AC, pulsed, mixed ..., with a galvanic isolation
between the primary circuit (high power)
and the secondary circuit (electronic circuit)

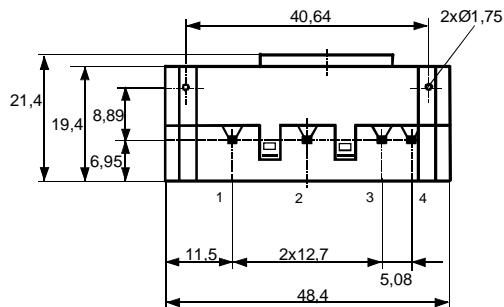

Date: 20.10.2010

Customer: Standard type

Customers Part no.:
Page 2 **of** 2

Mechanical outline (mm):

General tolerances DIN ISO 2768-c

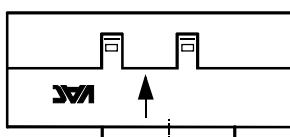
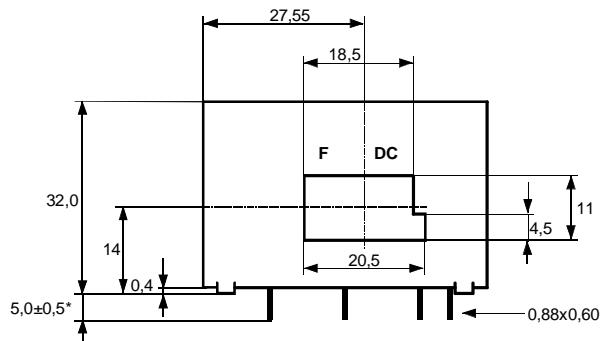
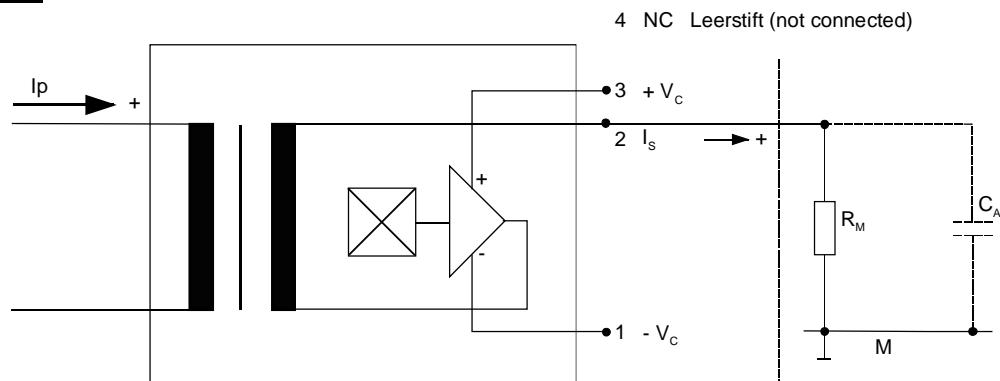

Toleranz der Stiftabstände $\pm 0,2\text{mm}$
(Tolerances grid distance)

DC = Date Code
F = Factory

*= vorläufig
(preliminary)

Connections:
1...4: 0,6 x 0,88 mm

Marking:

4646X200
F DC

Schematic diagram


Temperature of the primary conductor should not exceed 110°C

Additional indications are obtainable on request.

This specification is no declaration of warranty acc. BGB §443 dar.

Hrsg.: KB-E
editor

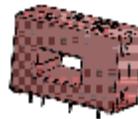
Bearb: Le.
designer

KB-PM: KRe
check

freig.: prs.
released

K-No.: 25150

125 A Current Sensor

 For electronic current measurement:
 DC, AC, pulsed, mixed ..., with a galvanic
 isolation between primary circuit
 (high power) and secondary circuit

Date: 20.10.2010

Customer:
Customers Part No.:
Page 1 of 3
Electrical Data (investigate by a type checking)

		min.	typ.	max.	Unit
V _{Ctot}	Maximum supply voltage (without function) ±15.75 to ±18 V: for 1s per hour			±18	V
R _S	Secondary coil resistance @ T _A =85°C			41	Ω
X _{Ti}	Temperature drift of X @ T _A = -40 ... +85 °C			0.1	%
I _{0ges}	Offset current (including I ₀ , I _{0t} , I _{0T})			0.14	mA
I _{0t}	Long term drift Offset current I ₀			0.05	mA
I _{0T}	Offset current temperature drift I ₀ @ T _A = -40 ... +85°C			0.05	mA
I _{0H}	Hysteresis current @ I _P =0 (caused by primary current 10 x I _{PN})	0.05		0.1	mA
ΔI ₀ /ΔV _C	Supply voltage rejection ratio			0.01	mA/V
i _{loss}	Offset ripple (with 1 MHz- filter first order)			0.1	mA
i _{loss}	Offset ripple (with 100 kHz- filter first order)	0.015		0.04	mA
i _{loss}	Offset ripple (with 20 kHz- filter first order)			0.007	mA
C _k	Maximum possible coupling capacity (primary – secondary)	7			pF

Inspection (Measurement after temperature balance of the samples at room temperature)

K _N (N ₁ /N ₂)	(V)	M3011/6	Transformation ratio (I _P =100A, 40-80 Hz)	1: 995...1005
I _P	(V)	M3011/4	Primary current	100 A
I ₀	(V)	M3226	Offset current	< 0.1 mA
V _d	(V)	M3014:	Test voltage, rms, 1 s pin 1 – 3 vs. hole	1.8 kV
V _e	(AQL 1/S4)		Partial discharge voltage acc.M3024 (RMS) with V _{vor} (RMS)	1300 V 1625 V

Type Testing (Pin 1 - 3 to hole)

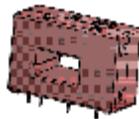
V _w	HV transient test according to M3064 (1,2 µs / 50 µs-wave form)	8	kV
V _d	Testing voltage to M3014	(5 s)	3.6 kV
V _e	Partial discharge voltage acc.M3024 (RMS) with V _{vor} (RMS)	1300 V 1625 V	V

Datum	Name	Index	Änderung
20.10.10	Le	81	Date updated.
Hrsg.: KB-E editor	Bearb: Le designer	KB-PM: KRe check	freig.: prs. released

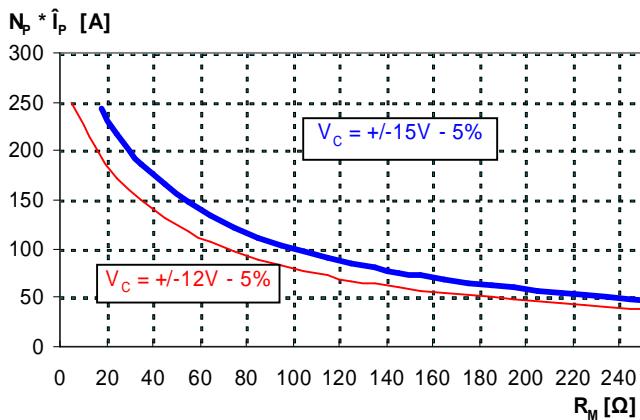
K-No.: 25150

125 A Current Sensor

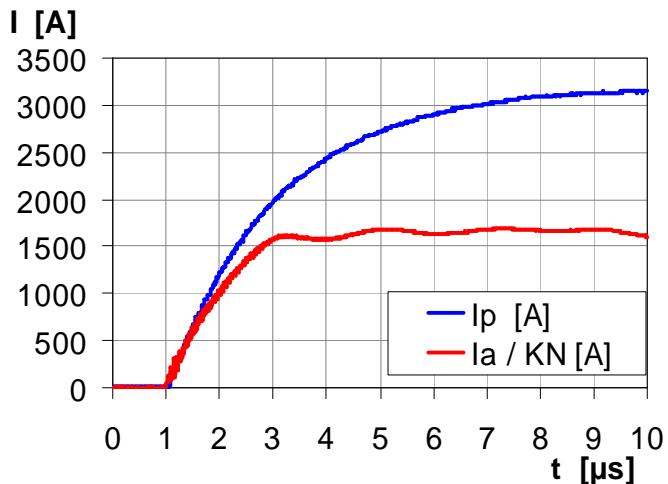
For electronic current measurement:
DC, AC, pulsed, mixed ..., with a galvanic
isolation between primary circuit
(high power) and secondary circuit


Date: 20.10.2010

Customer:
Customers Part No.:
Page 2 of 3
Limit curve of measurable current $\hat{I}_P(R_M)$

@ ambient temperature $\leq 85^\circ\text{C}$

Maximum measuring range ($\mu\text{s-range}$)

Output current behaviour of a 3kA current pulse
@ $V_C = \pm 15V$ und $R_M = 10\Omega$



Fast increasing currents (higher than the specified $I_{p,\max}$), e.g. in case of a short circuit, can be transmitted because the currents are transformed directly and be limited by diodes only.

The offset ripple can be reduced by an external low pass. Simplest solution is a passive low pass filter of 1st order with

$$f_g = \frac{1}{2p \cdot R_M \cdot C_a}$$

In this case the response time is enlarged.

It is calculated from:

$$t'_r \leq t_r + 2,5R_M C_a$$

Applicable documents

Current direction: A positive output current appears at point I_S , by primary current in direction of the arrow.

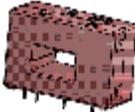
Housing and bobbin material UL-listed: Flammability class 94V-0.

HRsg.: KB-E
editor

Bearb.: Le
designer

KB-PM: KRE
check

freig.: prs.
released

K-No.: 25150	125 A Current Sensor For electronic current measurement: DC, AC, pulsed, mixed ..., with a galvanic isolation between primary circuit (high power) and secondary circuit		Date: 20.10.2010
--------------	---	--	------------------

Customer:	Customers Part No.:	Page 3 of 3
-----------	---------------------	-------------

Explanation of several of the terms used in the tablets (in alphabetical order)

I_{OH} : Zero variation after overloading with a DC of tenfold the rated value ($R_M = R_{MN}$)

I_{OT} : Long term drift of I_o after 100 temperature cycles in the range -40 bis 85 °C.

t_r : Response time, measured as delay time at $I_P = 0,8 \cdot I_{Pmax}$ between a rectangular current and the output current.

$\Delta t (I_{Pmax})$: Delay time between I_{Pmax} and the output current i_a with a primary current rise of $di_1/dt = 100 \text{ A}/\mu\text{s}$.

U_{PD} Rated discharge voltage (recurring peak voltage separated by the insulation) proved with a sinusoidal voltage V_e
 $U_{PD} = \sqrt{2} * V_e / 1,5$

V_{vor} Defined voltage is the RMS value of a sinusoidal voltage with peak value of $1,875 * U_{PD}$ required for partial discharge test in IEC 61800-5-1

$$V_{vor} = 1,875 * U_{PD} / \sqrt{2}$$

V_{sys} System voltage RMS value of rated voltage according to IEC 61800-5-1

V_{work} Working voltage voltage according to IEC 61800-5-1 which occurs by design in a circuit or across insulation

$X_{ges}(I_{PN})$: The sum of all possible errors over the temperature range by measuring a current I_{PN} :

$$X_{ges} = 100 \cdot \left| \frac{I_S(I_{PN})}{K_N \cdot I_{PN}} - 1 \right|$$

X : Permissible measurement error in the final inspection at RT, defined by

$$X = 100 \cdot \left| \frac{I_{SB}}{I_{SN}} - 1 \right|$$

where I_{SB} is the output DC value of an input DC current of the same magnitude as the (positive) rated current ($I_o = 0$)

X_{Ti} : Temperature drift of the rated value orientated output term. I_{SN} (cf. Notes on F_i) in a specified temperature range, obtained by:

$$X_{Ti} = 100 \cdot \left| \frac{I_{SB}(T_{A2}) - I_{SB}(T_{A1})}{I_{SN}} \right|$$

ϵ_L : Linearity fault defined by $\epsilon_L = 100 \cdot \left| \frac{I_P}{I_{PN}} - \frac{I_{Sx}}{I_{SN}} \right|$

Where I_P is any input DC and I_{Sx} the corresponding output term. I_{SN} : see notes of F_i ($I_o = 0$).

This "Additional information" is no declaration of warranty according BGB §443.

Hrsg.: KB-E	Bearb: Le		KB-PM: KRe		freig.: prs. released
-------------	-----------	--	------------	--	--------------------------

ООО "ЛайфЭлектроникс"

"LifeElectronics" LLC

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибуторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибуторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помочь разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)
Email: org@lifeelectronics.ru